

NOR Flash Parallel 3V/3.3V 128M-bit 16M x 8/8M x 16 70ns 64-Pin TBGA Tray

Manufacturers	<a href="#">STMicroelectronics, Inc</a>
Package/Case	BGA-64
Product Type	Memory
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for M29W128GL70ZA6E or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

M29W128GL70ZA6E is a flash memory chip manufactured by STMicroelectronics. Here are some of its features:

### Features

- It has a capacity of 128 Megabits (16 Megabytes)
- It uses a NOR Flash architecture
- It operates at a voltage range of 2.7V to 3.6V
- It has a 70 ns access time
- It has a 16-bit data bus width
- It has an 8 KB block erase size

### Application

- Embedded systems
- Consumer electronics
- Automotive electronics
- Industrial control systems

**STMicroelectronics**

Manufactured under patents or Patents pending  
Assembled in: MALAYSIA  
Pb-free 2nd Level Interconnect  
MSL: 03 Bas seal date: 03 Aug 2008  
PBT: 260 C Category: e2 ECOPACK/RoHS

TYPE: M29W128GL70ZA6E  
XC6XP7EMS99L706E

Total Qty: 816

Trace Codes 99830AKM US 99  
99830AUM US 99

Marking M29W128GL70ZA6

Bulk ID T89320MY0005



Please provide the bulk ID for any inquiry



bake  
5 hours

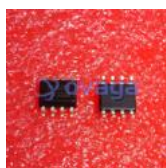


## Related Products



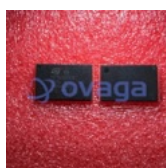
### [M24C16-WMN6P](#)

STMicroelectronics, Inc  
SOIC-8



### [M24512-DFMN6TP](#)

STMicroelectronics, Inc  
SOP8



### [M29W320EB70N6F](#)

ST  
TSOP-48



### [M24C02-FMC6TG](#)

STMicroelectronics, Inc  
QFN-8



### [M24C16-RDW6TP](#)

STMicroelectronics, Inc  
TSSOP-8



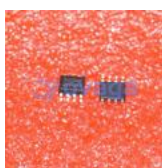
### [M25PE16-VMW6TG](#)

ST  
SOP-8



### [M29F032D-70N6](#)

STMicroelectronics, Inc  
TSOP-40



### [M24C04-WMN6P](#)

STMicroelectronics, Inc  
SOIC-8